TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOSVII)

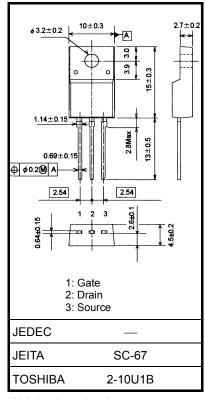
# TK4A60DA

#### Switching Regulator Applications

- Low drain-source ON resistance:  $RDS(ON) = 1.7 \Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 2.2 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 600 \ V)$
- Enhancement-mode:  $V_{th} = 2.4$  to 4.4 V ( $V_{DS} = 10$  V,  $I_D = 1$  mA)

Characteristics		Symbol	Rating	Unit		
Drain-source voltage			V <sub>DSS</sub>	600	V	
Gate-source voltage			V <sub>GSS</sub>	±30	V	
Drain current	DC (Note	1)	۱ <sub>D</sub>	3.5	Α	
	Pulse (Note	1)	I <sub>DP</sub>	14	A .	
Drain power dissipation (Tc = $25^{\circ}$ C)			PD	35	W	
Single pulse avalanche energy (Note 2)			E <sub>AS</sub>	158	mJ	
Avalanche current			I <sub>AR</sub>	3.5	А	
Repetitive avalanche energy (Note 3)			E <sub>AR</sub>	3.5	mJ	
Channel temperature			T <sub>ch</sub>	150	°C	
Storage temperature range			T <sub>stg</sub>	-55 to 150	°C	

#### Absolute Maximum Ratings (Ta = 25°C)



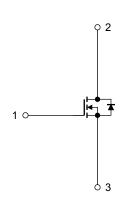
Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	3.57	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	62.5	°C/W

Internal Connection



Start of commercial production 2008-09

Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 22.5 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 3.5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Unit: mm

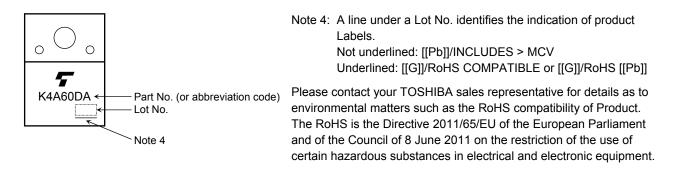
**Electrical Characteristics (Ta = 25°C)** 

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off current		I <sub>DSS</sub>	$V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	600	_		V
Gate threshold ve	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.4	_	4.4	V
Drain-source ON	resistance	R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1.8 \text{ A}$	_	1.7	2.2	Ω
Forward transfer	rward transfer admittance $ Y_{fs} $ $V_{DS} = 10 V_{r}$		$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1.8 \text{ A}$	0.6	2.2		S
Input capacitance		C <sub>iss</sub>		—	490		pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS}$ = 25 V, $V_{GS}$ = 0 V, f = 1 MHz	_	3		
Output capacitance		C <sub>oss</sub>			55		
Switching time	Rise time	tr	$V_{GS}$ $0 V$ $V_{GS}$ $0 V$ $V_{GS}$ $0 V$ $V_{DD} \approx 200 V$		18		ns
	Turn-on time	t <sub>on</sub>			40		
	Fall time	t <sub>f</sub>			8		
	Turn-off time	t <sub>off</sub>	Duty $\leq$ 1%, t <sub>w</sub> = 10 µs		55		
Total gate charge		Qg		_	11		
Gate-source charge		Q <sub>gs</sub>	$V_{DD}\approx 400$ V, $V_{GS}=10$ V, $I_{D}=3.5$ A		6		nC
Gate-drain charge		Q <sub>gd</sub>		_	5		

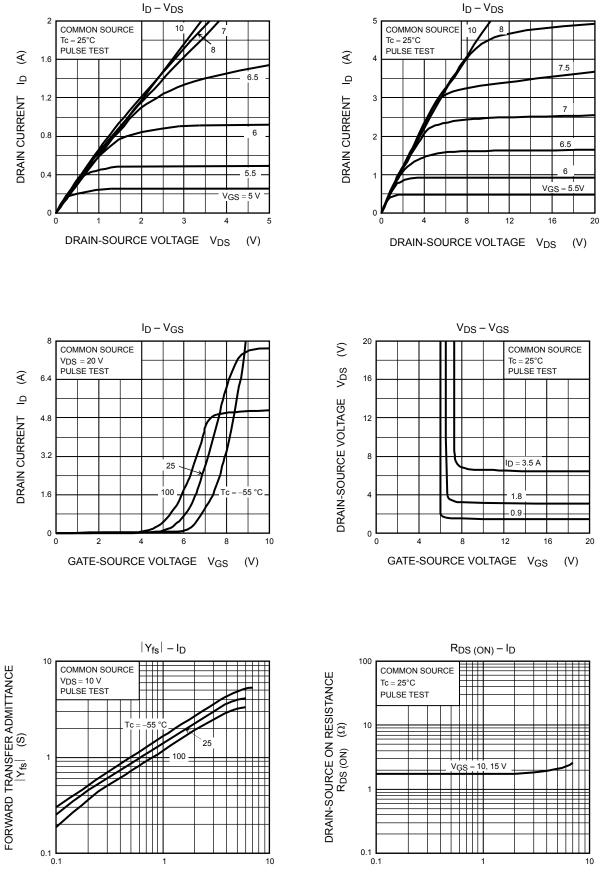
#### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—	_	_	3.5	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	14	А
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 3.5 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 3.5 \text{ A}, V_{GS} = 0 \text{ V},$	_	1000	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dI <sub>DR</sub> /dt = 100 A/μs	_	5.0	_	μC

#### Marking



## TOSHIBA



DRAIN CURRENT ID (A)

2013-11-01

DRAIN CURRENT ID (A)

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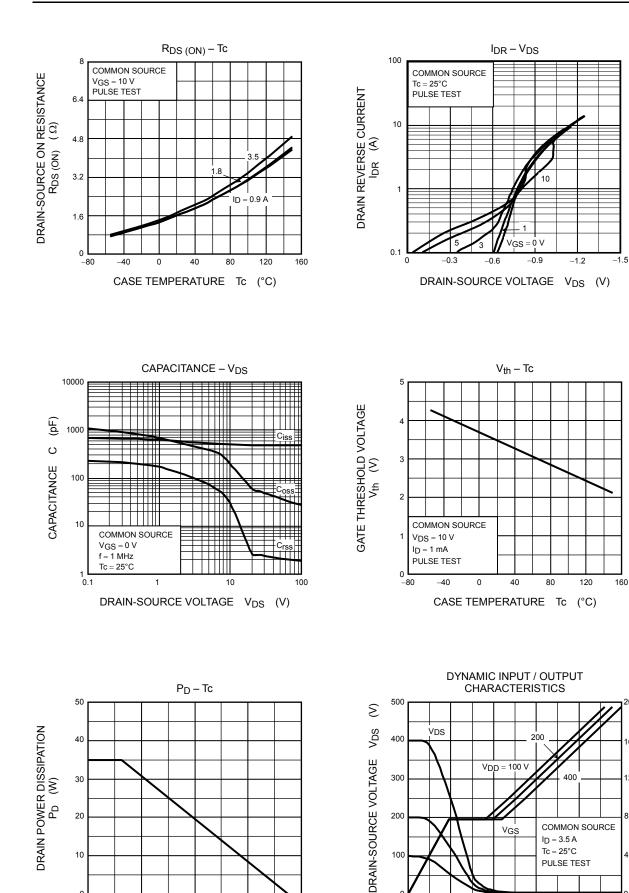
40

80

CASE TEMPERATURE Tc (°C)

120

160



20

16

12

n

20

PULSE TEST

16

(nC)

12

S

Vgs

GATE-SOURCE VOLTAGE

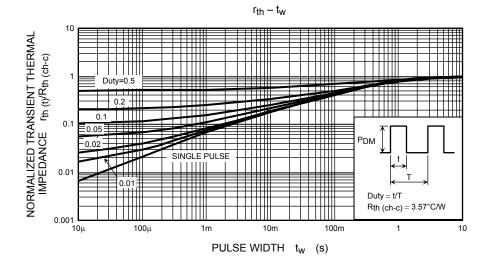
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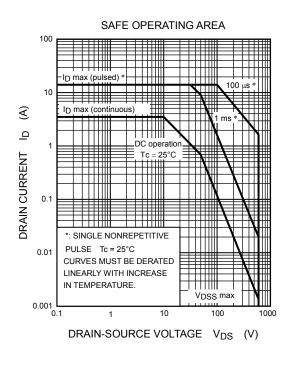
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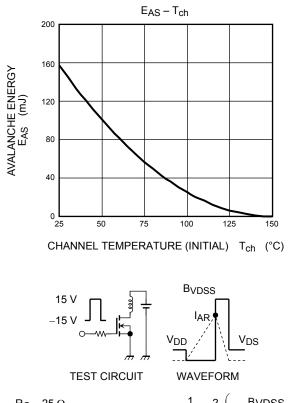
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8

TOTAL GATE CHARGE Qg







 $\begin{array}{l} \mathsf{R}_{G} = 25 \ \Omega \\ \mathsf{V}_{DD} = 90 \ \mathsf{V}, \ \mathsf{L} = 22.5 \ \mathsf{mH} \end{array} \qquad \mathsf{E}_{AS} = \frac{1}{2} \cdot \mathsf{L} \cdot \mathsf{I}^{2} \cdot \left( \frac{\mathsf{B}_{VDSS}}{\mathsf{B}_{VDSS} - \mathsf{V}_{DD}} \right) \\ \end{array}$ 

5

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